# Dual Low-Voltage TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

Ultra Low V<sub>F</sub> = 0.34 V at I<sub>F</sub> = 2.5 A





## ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5.0 A				
V <sub>RRM</sub>	45 V				
I <sub>FSM</sub>	100 A				
V <sub>F</sub> at I <sub>F</sub> = 5.0 A	0.41 V				
T <sub>J</sub> max.	150 °C				
Package SMPD (TO-263AC)					
Circuit configuration	Common cathode				

### **FEATURES**

### Trench MOS Schottky technology

- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified available - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V10D45C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	45	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	10	^	
	per diode		5	A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	100	A	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

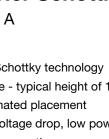
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Available

RoHS COMPLIANT

HALOGEN FREE









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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	– T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V	
	I <sub>F</sub> = 5.0 A			0.50	0.58		
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.34	-		
	I <sub>F</sub> = 5.0 A			0.41	0.50		
Reverse current per diode	V <sub>R</sub> = 45 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	500	μA	
	$v_{\rm R} = 43$ V $T_{\rm A}$	T <sub>A</sub> = 125 °C		3	15	mA	

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V10D45C	UNIT	
Typical thermal resistance	per diode	$R_{ extsf{ heta}JC}$	3.5		
	per device		2.5	°C/W	
	per device	R <sub>0JA</sub> (1)(2)	48		

#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

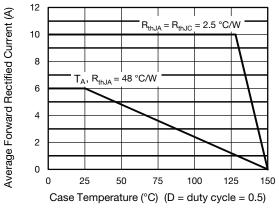
<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
V10D45C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel			
V10D45CHM3_A/I (1)	0.55	Ι	2000/reel	13" diameter plastic tape and reel			

Note

(1) AEC-Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





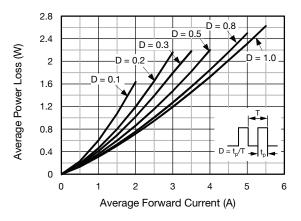
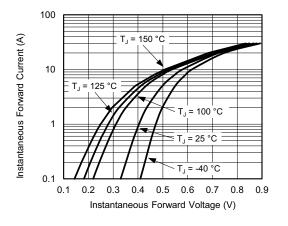


Fig. 2 - Forward Power Loss Characteristics Per Diode

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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

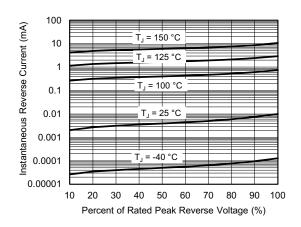


Fig. 4 - Typical Reverse Characteristics Per Diode

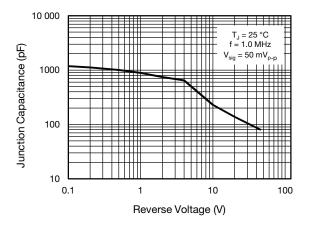


Fig. 5 - Typical Junction Capacitance Per Diode

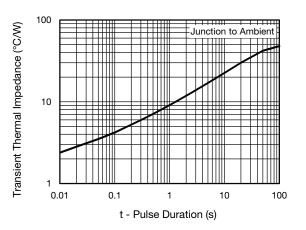


Fig. 6 - Typical Transient Thermal Impedance Per Diode

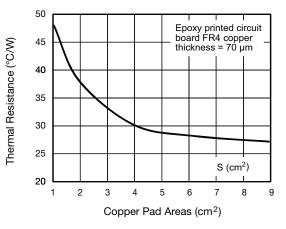


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

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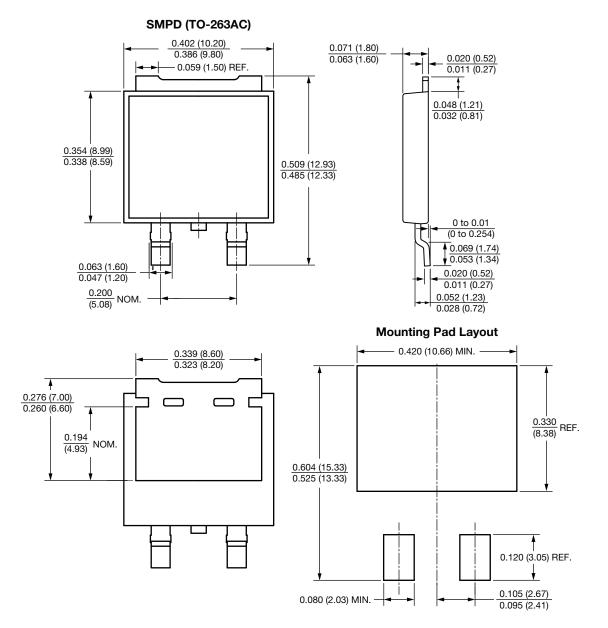
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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